Pumping and population inversion

Laser amplification

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Upper-level laser Three-level laser Solve rate-equations under transients

Atomic transitions



Energy-level diagram of Nd:YAG

Simplify into ->





"Optical approximation", $\hbar\omega/k_BT \ll 1$ No thermal occupancy



At steady state:

$$N_{3} = \frac{\tau_{3}}{\tau_{43}} N_{4}$$
Define beta
$$N_{2} = \left(\frac{\tau_{21}}{\tau_{32}} + \frac{\tau_{43}\tau_{21}}{\tau_{42}\tau_{3}}\right) N_{3} \equiv \beta N_{3}$$

For a good laser: No direct decay into lev2 $\gamma_{42} \approx 0 \ (i. e. \ \tau_{42} \rightarrow \infty),$

 $\Rightarrow \quad \rightarrow \beta \approx \frac{\tau_{21}}{\tau_{32}}$

Fluorescent quantum efficiency, $\eta \equiv \frac{\tau_4}{\tau_{43}} \cdot \frac{\tau_3}{\tau_{rad}}$ Useful photons: from 4 -> upper laser *
From upper laser that lase 4-level laser

Calculate the pop. Inv.

Population inversion,

$$\frac{N_3 - N_2}{N} = \frac{(1 - \beta)\eta W_p \tau_{rad}}{1 + \left(1 + \beta + \frac{2\tau_{43}}{\tau_{rad}}\right)\eta W_p \tau_{rad}}$$

For a good laser:

 $\tau_{43} \ll \tau_{rad}$

 $\eta \rightarrow 1$

- Short lev 4 lifetime

 $\beta \approx \tau_{21}/\tau_{32} \rightarrow 0$ - Short lower lev lifetime

High fluorescent quantum efficiency

$$\Rightarrow \frac{N_3 - N_2}{N} \approx \frac{W_p \tau_{rad}}{1 + W_p \tau_{rad_{-}}} \quad \text{Red curves}$$





3-level laser

As before, for 3-level



3-level laser

No pumping NEGATIVE pop. Inv. At steady state, $N_2 - N_1 \quad (1 - \beta)\eta W_n \tau_{rad} - 1$

$$\frac{N_2 - N_1}{N} = \frac{(1 - \beta)\eta W_p \tau_{rad} - 1}{(1 + 2\beta)\eta W_p \tau_{rad} + 1}$$

Requirements for pop. inversion:

eta < 1 As before $W_p au_{rad} \geq rac{1}{\eta(1-eta)}$ New

For a good laser, $\beta \rightarrow 0$ $\eta \rightarrow 1$

$$\frac{N_2 - N_1}{N} \approx \frac{W_p \tau_{rad} - 1}{W_p \tau_{rad} + 1}$$

Red curves



Population inversion





Lasing between two levels high above ground-level

$$\frac{dN_3}{dt}_{pump} = W_p(N_0 - N_3)^{\text{Pump into upper lev.}}$$

Assuming, $N_0 \approx N \gg N_3$ and pump efficiency, η_p , $\frac{dN_3}{dt}_{pump} \approx \eta_p W_p N \equiv R_p$ state

Rate equations:

$$\frac{dN_2}{dt} = R_p - W_{sig}(N_2 - N_1) - \gamma_2 N_2$$
$$\frac{dN_1}{dt} = W_{sig}(N_2 - N_1) + \gamma_{21}N_2 - \gamma_1 N_1$$



At steady state:

$$N_1 = \frac{W_{sig} + \gamma_{21}}{W_{sig}(\gamma_1 + \gamma_{20}) + \gamma_1\gamma_2} R_p$$

$$N_2 = \frac{W_{sig} + \gamma_1}{W_{sig}(\gamma_1 + \gamma_{20}) + \gamma_1\gamma_2} R_p$$

No atom conservation!

For example, changing pump changes N

The pop. Inv. Saturates as the signal increases

Population inversion:

$$\Delta N_{21} = N_2 - N_1 = \left(\frac{\gamma_1 - \gamma_{21}}{\gamma_1 \gamma_2}\right) \cdot \frac{R_p}{1 + \left[\frac{\gamma_1 + \gamma_{20}}{\gamma_1 \gamma_2}\right] W_{sig}}$$

Define the small-signal population inversion, $\Delta N_0 = \frac{\gamma_1 - \gamma_{21}}{\gamma_1 \gamma_2} R_p$ and the effective recovery time, $\tau_{eff} = \tau_2 \left(1 + \frac{\tau_1}{\tau_{20}}\right)$ the expression becomes:

$$\Delta N_{21} = \Delta N_0 \frac{1}{1 + W_{sig} \tau_{eff}}$$

For a good laser:

 $\begin{array}{l} \gamma_2 \approx \gamma_{21} \\ \gamma_{20} \approx 0 \end{array}$

$$\rightarrow \Delta N_{21} \approx R_p (\tau_2 - \tau_1) \cdot \frac{1}{1 + W_{sig} \tau_2}$$

Prop. To pump-rate and lifetimes, saturation behavior

• Condition for obtaining inversion,

 $\tau_1/\tau_{21} < 1$

i.e. fast relaxation from lower level and slow relaxation from upper level

• Small-signal gain,

$$\Delta N_0 \sim R_p \cdot \frac{\tau_2}{1 - \tau_1 / \tau_{21}}$$

i.e. small-signal gain is proportional to the pump-rate times a reduced upper-level lifetime

• Saturation behavior,

$$\Delta N_{21} = \Delta N_0 \cdot \frac{1}{1 + W_{sig} \tau_{eff}}$$

i.e. the saturation intensity depends only on the signal intensity and the effective lifetime, not on the pumping rate.

Upper-level laser: Transient rate equation

As for instance before a Q-switched pulse

Assume: No signal ($W_{sig} = 0$), fast lower-level relaxation ($N_1 \approx 0$), $dN_1(t)$

$$\frac{dN_2(t)}{dt} = R_p(t) - \gamma_2 N_2(t)$$

The upper level population becomes,

$$N_2(t) = \int_{-\infty}^t R_p(t') e^{-\gamma_2(t-t')} dt'$$

Applying a square pulse,

$$N_2(T_p) = R_{p0}\tau_2(1 - e^{-T_p/\tau_2})$$

Define the pump efficiency,

$$\eta_p = \frac{N_2(t = T_p)}{R_{p0}T_p} = \frac{1 - e^{-T_p/\tau_2}}{T_p/\tau_2}$$

^Pop. In upper lev per pump-photon



3-level laser: pulses

3-level laser from prev, no signal

Assume: No signal ($W_{sig} = 0$), Fast upper-level relaxation ($\tau_3 \approx 0$),



Simple model-agrees with experiment!

$$\frac{\Delta N(T_p)}{N} \approx 1 - 2e^{-W_p T_p}$$

Summary

Steady state laser pumping and population inversion

4-level laser

$$\frac{N_3 - N_2}{N} \approx \frac{W_p \tau_{rad}}{1 + W_p \tau_{rad}}$$

3-level laser

$$\frac{N_2 - N_1}{N} \approx \frac{W_p \tau_{rad} - 1}{1 + W_p \tau_{rad}}$$

Difference between three and four-level systems, and why four-level systems are superior

Laser gain saturation

Upper-level laser, saturation behavior

$$\Delta N_{21} = \Delta N_0 \cdot \frac{1}{1 + W_{sig} \tau_{eff}}$$

Transient rate equations

Upper-level laser

$$\eta_p = \frac{N_2(t = T_p)}{R_{p0}T_p} = \frac{1 - e^{-T_p/\tau_2}}{T_p/\tau_2}$$

Three-level laser

$$\frac{\Delta N(T_p)}{N} \approx 1 - 2e^{-W_p T_p}$$

Saturation intensity is **independent** of the

pumping-rate "i.e. The signal intensity needed to reduce the pop. Inv. To half its initial value doesn't depend on the pumping rate"

Short pulses are needed to obtain high pumping efficiency

These simple models give good agreement with reality

Contents

Part II: Laser amplification

Wave propagation in atomic media

Plane-wave approximation The paraxial wave equation

Solve wave-eqs

Single-pass laser amplification

Gain narrowing Transition cross-sections Gain saturation Power extraction

See effects on the gain

Maxwell's equations: $\nabla x E = -j\omega B$ $\nabla x H = J + j\omega D$

Constitutive relations:

 $B = \mu H$ $J = \sigma E$ $D = \epsilon E + P_{at} = \epsilon [1 + \chi_{at}] E$

Vector field of the form:

$$\boldsymbol{\epsilon}(\boldsymbol{r},t) = \frac{1}{2} \left[\boldsymbol{E}(\boldsymbol{r}) e^{j\omega t} + c.c \right]$$

Assume a spatially uniform material ($\nabla \cdot E = 0$), and apply $\nabla \times$ to get the wave equation:

$$\left[\nabla^2 + \omega^2 \mu \epsilon \left(1 + \tilde{\chi}_{at} - \frac{j\sigma}{\omega\epsilon}\right)\right] \tilde{E}(x, y, z) = 0$$

Material parameters: $\mu - magnetic permeability$ $\sigma - ohmic losses$ $\epsilon - dielectric permittivity (not counting$ atomic transitions) $<math>\chi_{at}(\omega) - resonant$ susceptibility due to laser transitions Plane-wave approximation

Consider a plane wave,

 $\left|\frac{\partial^2 \tilde{E}}{\partial x^2}\right|, \left|\frac{\partial^2 \tilde{E}}{\partial y^2}\right| \ll \left|\frac{\partial^2 \tilde{E}}{\partial z^2}\right|$

i.e.
$$\nabla^2 \rightarrow \frac{d^2}{dz^2}$$

The equation reduces to:

$$\left[d_z^2 + \omega^2 \mu \epsilon \left(1 + \tilde{\chi}_{at} - \frac{j\sigma}{\omega \epsilon}\right)\right] \tilde{E}(z) = 0$$



Plane-wave approximation

Without losses:

First, no losses

 $[d_z^2 + \omega^2 \mu \epsilon] \tilde{E}(z) = 0,$

Assume solutions on the form: $\tilde{E}(z) = const \cdot e^{-\Gamma z}$

 $\Rightarrow [\Gamma^2 + \omega^2 \mu \epsilon] \tilde{E} = 0$

The allowed values for Γ are, $\Gamma = \pm j\omega\sqrt{\mu\epsilon} \equiv \pm j\beta$

With the solution,

$$\boldsymbol{\epsilon}(z,t) = \frac{1}{2} \left[E_{+} e^{j(\omega t - \beta z)} + E_{+}^{*} e^{-j(\omega t - \beta z)} \right] + \frac{1}{2} \left[E_{-} e^{j(\omega t + \beta z)} + E_{-}^{*} e^{-j(\omega t + \beta z)} \right]$$

The free space propagation constant, β , may be written:

$$\beta = \omega \sqrt{\mu \epsilon} = \frac{\omega}{c} = \frac{2\pi}{\lambda}$$

Different beta from last chapter Plane-wave approximation

Put losses back

With laser action and losses:

$$\left[d_z^2 + \beta^2 \left(1 + \tilde{\chi}_{at} - \frac{j\sigma}{\omega\epsilon}\right)\right] \tilde{E}(z) = 0$$

Assuming
$$\tilde{E}(z) = const \cdot e^{-\Gamma z}$$
, as before:

$$\Gamma = j\beta \sqrt{1 + \tilde{\chi}'_{at}(\omega) + j\tilde{\chi}''_{at}(\omega) - j\sigma/\omega\epsilon}$$

Normally,
$$\tilde{\chi}_{at}(\omega), \frac{\sigma}{\omega\epsilon} \ll 1$$
:
 $\sqrt{1+\delta} \approx 1 + \frac{\delta}{2}$

$$\Gamma \approx j\beta \left[1 + \frac{1}{2}\chi'_{at}(\omega) + \frac{j}{2}\chi''_{at}(\omega) - \frac{j\sigma}{2\omega\epsilon} \right] = j\beta + j\Delta\beta_m(\omega) - \alpha_m(\omega) + \alpha_0$$

Define four terms

The final solution becomes:

$$\boldsymbol{\epsilon}(z,t) = Re\tilde{E}_0 \exp[j\omega t - j[\beta + \Delta\beta_m(\omega)]z + [\alpha_m(\omega) - \alpha_0]z]$$

Propagation Factors

$$\boldsymbol{\epsilon}(z,t) = Re\tilde{E}_0 \exp[j\omega t - j[\beta + \Delta\beta_m(\omega)]z + [\alpha_m(\omega) - \alpha_0]z]$$

Phase-shift loss/gain

Linear phase-shift (Red)

 β – Plane-wave propagation constant, fundamental phase variation,

Nonlinear phase-shift (Blue)

 $\Delta\beta_m(\omega)$ – Additional atomic phaseshift due to population inversion

→ Total phase-shift (Green)

Gain (Orange) $\alpha_m(\omega)$ – Atomic gain or loss coefficient (due to transitions)

Background

 α_0 – Ohmic background loss



Exceptions

Larger atomic gain or absorption effects

The results so far are based on the assumption that $\left| \tilde{\chi}_{at} - \frac{j\sigma}{\omega \epsilon} \right| \ll 1$, however, there are a few situations of interest where this doesn't hold:

- Absorption in metals and semiconductors, at frequencies higher than the bandgap **energy**, the effective conductivity, σ can become very large **Big sigma**
- Absorption on **strong resonance lines** in metal vapor, the transitions are very strongly allowed giving a high absorption per unit length **Big chi**

The paraxial wave equation

Want to handle transverse variations

The full wave-equation,

$$\left[\nabla^2 + \beta^2 \left(1 + \tilde{\chi}_{at} - \frac{j\sigma}{\omega\epsilon}\right)\right] \boldsymbol{E}(\boldsymbol{r}) = 0$$

New ansatz,

$$\tilde{E}(\mathbf{r}) \equiv \tilde{u}(\mathbf{r})e^{-j\beta z}$$
 change const -> u(r)

Insert into the wave equation,

$$\left[\frac{\partial^2 \widetilde{u}}{\partial x^2} + \frac{\partial^2 \widetilde{u}}{\partial y^2} + \frac{\partial^2 \widetilde{u}}{\partial z^2} - 2j\beta \frac{\partial \widetilde{u}}{\partial z} - \beta^2 \widetilde{u}\right] e^{-j\beta z} = 0$$

Assume that $\tilde{u}(\mathbf{r})$ changes slowly along the z-direction,

$$\left|\frac{\partial^2 \tilde{u}}{\partial z^2}\right| \ll \left|2\beta \frac{\partial \tilde{u}}{\partial z}\right|$$

and

$$\left|\frac{\partial^2 \tilde{u}}{\partial z^2}\right| \ll \left|\frac{\partial^2 \tilde{u}}{\partial x^2}\right|, \left|\frac{\partial^2 \tilde{u}}{\partial y^2}\right|$$

"Paraxial wave equation"

$$\Rightarrow \nabla_t^2 \tilde{u} - 2j\beta \frac{\partial \tilde{u}}{\partial z} + \beta^2 \left(\tilde{\chi}_{at} - \frac{j\sigma}{\omega \epsilon} \right) \tilde{u} = 0$$

Diffraction- and propagation effects

Rewrite:

Re-write the equation

$$\frac{\partial \tilde{u}(\boldsymbol{r})}{\partial z} = -\frac{j}{2\beta} \nabla_t^2 \tilde{u}(\boldsymbol{r}) - [\alpha_0 - \alpha_m + j\Delta\beta_m] \tilde{u}(\boldsymbol{r})$$

 $\alpha_0, \alpha_m(\omega)$, and $j\Delta\beta_m(\omega)$ are defined as before

Four terms, same as before

Two terms:

Diffraction,

$$-\frac{j}{2\beta}\nabla_t^2$$

Ohmic and atomic gain/loss, $-[\alpha_0 - \alpha_m + j\Delta\beta_m]$

Separate terms -> Independent to first order, gain and phase-shift results are the same as for plane waves

Reproduce the plane-wave result



An elementary single-pass laser amplifier.

Calculate the gain

The laser gain after length L:

$$\tilde{g}(\omega) \equiv \frac{\tilde{E}(L)}{\tilde{E}(0)}$$

In terms of intensity,

$$G(\omega) = \frac{I(L)}{I(0)} = \frac{\left|\tilde{E}(L)\right|^2}{\left|\tilde{E}(0)\right|^2} = \exp[2\alpha_m(\omega)L - 2\alpha_0 L] = \exp[\beta\chi''(\omega)L - \frac{\sigma}{\epsilon c}L]$$

For most lasers, $\alpha_0 \ll \alpha_m \Rightarrow$

 $G(\omega) \approx \exp(\beta \chi''(\omega)L)$

exponential dependence on chi

Gain narrowing



 $2(\omega - \omega_a)/\Delta \omega_a$

Absorbing media have opposite sign of $\chi(\omega)$

 \rightarrow "Absorption broadening"

Uninverted population -> absorption broadening



Power transmission versus frequency

Stimulated transition cross-sections



The cross-sections are related,

$$g_1\sigma_{12} = g_2\sigma_{21}$$

Convert power \rightarrow intensity: $\frac{1}{l} \frac{dI}{dz} = -\Delta N_{12} \sigma_{21}$

Previously:

$$\frac{1}{l}\frac{dl}{dz} = -2\alpha_m(\omega)$$

Loss or gain can be calculated from cross-sections and atomic density

$$\Rightarrow 2\alpha_m(\omega) = \Delta N_{12}\sigma_{21}(\omega)$$

Cross-section formula

Using the full expression for χ :

From previous page: $2\alpha_m(\omega) = \Delta N_{12}\sigma_{21}(\omega)$

From definition of α : $\alpha_m(\omega) = \frac{\pi \chi''(\omega)}{\lambda}$ $\Rightarrow 2\alpha_m(\omega) = \Delta N\sigma(\omega) = \frac{2\pi}{\lambda} \chi''(\omega)$

2*1/,

The cross-section is a function of wavelength, transition rate and lineshape

$$\sigma(\omega_a) = \frac{3}{2\pi} \frac{\gamma_{rad}}{\Delta \omega_a} \lambda^2 \cdot \frac{1}{1 + [2(\omega - \omega_a)/\Delta \omega_a]^2}$$

1

Cross-section estimation: Estimate the max cross-section Assume, $\Delta \omega_a \equiv \gamma_{rad.}$ (purely radiative transmission), $3 = 3^*$, (all atoms aligned)

$$\Rightarrow \sigma_{max} = \frac{3\lambda^2}{2\pi} \approx \frac{\lambda^2}{2} \approx 10^{-9} cm^2$$

The cross section is far greater than the area of an atom, due to its **internal resonance**.

Real cross-sections

Typical Laser Transition Cross Sections			
Laser system	Transition cross section σ		
Gas lasers in the visible and near IR	10^{-11} to 10^{-13} cm ²		
Low-pressure CO_2 laser (10.6 μ m)	$3 imes 10^{-18} \mathrm{cm}^2$		
Organic dye laser (Rhodamine 6G)	1 to $2 \times 10^{-16} \text{cm}^2$		
Nd ³⁺ ion in Nd:YAG	$4.6\times 10^{-19} \mathrm{cm}^2$		
Nd ³⁺ ion in Nd:glass	$3 \times 10^{-20} \mathrm{cm}^2$		
Cr ³⁺ ion in ruby	$2 \times 10^{-20} \mathrm{cm}^2$		

TABLE 7.1 Typical Laser Transition Cross Sections



Allowed transitions in gas and non-allowed in solids -> $au_{gas} \ll au_{solid}$

Population difference saturation

Gain saturation, In a medium,

$$\frac{dI}{dz} = \pm 2\alpha_m I = \pm \Delta N \sigma I$$

As shown previously, ΔN saturates according to:

$$\Delta N = \Delta N_0 \cdot \frac{1}{1 + W \tau_{eff}} = \Delta N_0 \cdot \frac{1}{1 + I/I_{sat}}$$

 N_0 - unsaturated or small signal gain I_{sat} - saturation intensity

As ΔN saturates, the **gain saturates**

Stimulated-transition probability,

From before, $\Delta P_{abs} = (N_1 \sigma_{12} - N_2 \sigma_{21}) \cdot P \Delta z$

From rate equation analysis, $\Delta P_{abs} = (W_{12}N_1 - W_{21}N_2)A\Delta z\hbar\omega_a$

$$\Rightarrow W = \frac{\sigma I}{\hbar \omega}$$

i.e. the cross-section, the intensity and the stimulated transition probability are interdependent

Population difference saturation

At the line center:

From previous slide,

$$2\alpha_m(\omega, I) = \frac{\Delta N_0}{1 + I/I_{sat}} = \frac{\Delta N_0 \sigma}{1 + (\sigma \tau_{eff}/\hbar\omega)I}$$
Re-arrange prev
expressions
$$\rightarrow I_{sat} \equiv \frac{\hbar\omega}{\sigma \tau_{eff}}$$

i.e. $I = I_{sat}$: one incident photon within the cross-section per recovery time

Off center:

The expression is modified by the lineshape,

$$2\alpha_m(\omega, I) = \frac{\Delta N_0 \sigma}{1 + \frac{I}{I_{sat}} \cdot \frac{1}{1 + y^2}}$$

Where y is the normalized frequency detuning,

$$y=2(\omega-\omega_0)/\Delta\omega$$

Frequency dependence due to, transition lineshape and saturation behavior

Practical values

From previous slide,

$$I_{sat} \equiv \frac{\hbar\omega}{\sigma\tau_{eff}}$$

I-sat varies a lot between materials

 I_{sat} is an important parameter since little only little gain will be obtained once the intensity approaches this level.

Laser type:	ħω	σ	$ au_{eff}$	I _{sat}
Gas	10 ⁻¹⁹ J	10 ⁻¹³ cm ²	10 ⁻⁶ s	1 W /cm ²
Solid-state	10 ⁻¹⁹ J	10 ⁻¹⁹ cm ²	10 ⁻³ s	1 kW /cm ²

 I_{sat} is **independent** of the **pumping intensity**, since neither σ nor τ_{eff} are intensity dependent.

However, harder pumping does increase the small-signal gain

Saturation in laser amplifiers

Calculate the saturation

As a signal passes through an amplifier, it grows exponentially with distance until the intensity approaches I_{sat}

For a single pass amplifier:

$$\frac{1}{I(z)}\frac{dI}{dz} = 2\alpha_m(I) = \frac{2\alpha_{m0}}{1 + I(z)/I_{sat}}$$

Integrating,

$$\int_{I=I_{in}}^{I=I_{out}} \left[\frac{1}{I} + \frac{1}{I_{sat}}\right] dI = 2\alpha_{m0} \int_{z=0}^{z=L} dz$$

gives:

$$\ln\left(\frac{I_{out}}{I_{in}}\right) + \frac{I_{out} - I_{in}}{I_{sat}} = 2\alpha_{m0}L = \ln(G_0)$$

where, G_0 is the small-signal gain





Saturation in laser amplifiers

The total gain,

$$G \equiv \frac{I_{out}}{I_{in}} = G_0 \cdot \exp(-\frac{I_{out} - I_{in}}{I_{sat}})$$

Is the unsaturated gain, reduced by a factor exponentially dependent on $I_{out} - I_{in}$



FIGURE 7.12 Gain saturation as a function of distance along a single-pass laser amplifier.



Normalized Output and



Plotting the normalized output intensity vs the normalized input intensity, it is clear that the **transmission tends to unity** as the **input intensity is increased** -The amplifier becomes **transparent**.

Power-extraction

Define the extracted intensity,

Calculate the extracted power

$$I_{extr} \equiv I_{out} - I_{in} = \ln\left(\frac{G_0}{G}\right) \cdot I_{sat}$$

As the amplifier saturates, $G \rightarrow 1$,

$$I_{avail} = \lim_{G \to 1} \ln\left(\frac{G_0}{G}\right) \cdot I_{sat} = \ln(G_0) \cdot I_{sat}$$

Using $\ln(G_0) = 2\alpha_{m0}L$:

$$I_{avail} = 2\alpha_{m0}L \cdot I_{sat} = (\Delta N_0 \sigma L) \cdot \left(\frac{\hbar\omega}{\sigma\tau_{eff}}\right)$$

And re-writing:

$$\frac{I_{avail}}{L} \equiv \frac{P_{avail}}{V} = \frac{\Delta N_0 \hbar \omega}{\tau_{eff}}$$

i.e. the maximum available power is the total inversion energy, $\Delta N_0 \hbar \omega$, once every recovery time, τ_{eff}

Power-extraction efficiency

Full power extraction requires complete saturation of the amplifier which gives low small-signal gain.

Define the extraction efficiency,

$$\eta_{extr} \equiv \frac{I_{extr}}{I_{avail}} = \frac{\ln(G_0) - \ln(G)}{\ln(G_0)} = 1 - \frac{G_{dB}}{G_{0,dB}}$$

i.e. there's a tradeoff between **effiency** and **small-signal gain** for single-



Summary

Wave propagation in atomic media

Plane-wave approximation, $\left[d_z^2 + \beta^2 \left(1 + \tilde{\chi}_{at} - \frac{j\sigma}{\omega\epsilon}\right)\right] \tilde{E}(z) = 0$

The paraxial wave equation,

$$\frac{\partial \widetilde{u}(\mathbf{r})}{\partial z} = -\frac{j}{2\beta} \nabla_t^2 \widetilde{u}(\mathbf{r}) - [\alpha_0 - \alpha_m + j\Delta\beta_m] \widetilde{u}(\mathbf{r}) \quad \alpha_0 - \text{Ohmic background loss}$$

Single-pass laser amplification

Gain narrowing, $G(\omega) \sim \exp[\chi''(\omega)]$

Transition cross-sections, $2\alpha_m(\omega) = \Delta N_{12}\sigma_{21}(\omega)$

Gain saturation,

$$G = G_0 \cdot \exp(-\frac{I_{out} - I_{in}}{I_{sat}})$$

Power extraction,

$$\eta_{extr} = 1 - \frac{G_{dB}}{G_{0,dB}}$$

 β – Plane-wave propagation constant, fundamental phase variation,

 $\Delta\beta_m(\omega)$ – Additional atomic phaseshift due to population inversion

 $\alpha_m(\omega)$ – Atomic gain or loss coefficient (due to transitions)

Diffraction and gain are separate to first order

30-40% lower FWHM bandwidth

Loss/gain can be calculated from atomic density and cross-sections

Low signal gain is saturated by a factor exponentialy dependent on the intensity difference

There's a tradeoff between efficiency and small-signal gain